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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/611,645	06/30/2003	Hung-Jen Hsu	TSM03-0463	2071	
43859	7590 07/01/2004		EXAMINER		
	TAIWAN SEMICONDUCTOR MANUFACTURING CO., LTD. C/O SLATER & MATSIL, L.L.P.			MCPHERSON, JOHN A	
	R & MATSIL, L.L.P. TON ROAD, SUITE 100	0	ART UNIT	PAPER NUMBER	
DALLAS, T	•		1756		

DATE MAILED: 07/01/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

1 9	Application No.	Applicant(s)	
	10/611,645	HSU ET AL.	·, ·
Office Action Summary	Examiner	Art Unit	•
	John A. McPherson	1756	-
The MAILING DATE of this communication Period for Reply	on appears on the cover sheet with	the correspondence address	. :
A SHORTENED STATUTORY PERIOD FOR F THE MAILING DATE OF THIS COMMUNICAT - Extensions of time may be available under the provisions of 37 (after SIX (6) MONTHS from the mailing date of this communicat - If the period for reply specified above is less than thirty (30) days - If NO period for reply is specified above, the maximum statutory - Failure to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	ION. CFR 1.136(a). In no event, however, may a region. 5, a reply within the statutory minimum of thirty period will apply and will expire SIX (6) MONT y statute, cause the application to become ABA	oly be timely filed (30) days will be considered timely. HS from the mailing date of this communicati NDONED (35 U.S.C.§ 133).	ion
Status			
1) Responsive to communication(s) filed on	<u>06 October 2003</u> .		
2a) ☐ This action is FINAL . 2b) ∑	This action is non-final.		
3) Since this application is in condition for a closed in accordance with the practice un			is
Disposition of Claims			i i .
4) ⊠ Claim(s) <u>1-28</u> is/are pending in the application 4a) Of the above claim(s) is/are with 5) □ Claim(s) is/are allowed. 6) □ Claim(s) is/are rejected. 7) □ Claim(s) is/are objected to. 8) ⊠ Claim(s) <u>1-28</u> are subject to restriction are	thdrawn from consideration.		
Application Papers			
9) The specification is objected to by the Ex	aminer.		
10)⊠ The drawing(s) filed on <u>06 October 2003</u>	is/are: a)⊠ accepted or b)□ ob	jected to by the Examiner.	
Applicant may not request that any objection	to the drawing(s) be held in abeyand	e. See 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the call to be seen at the ca	,	· •	(d).
Priority under 35 U.S.C. § 119			
12) ☐ Acknowledgment is made of a claim for for a) ☐ All b) ☐ Some * c) ☐ None of: 1. ☐ Certified copies of the priority documents. ☐ Copies of the priority documents. ☐ Copies of the certified copies of the application from the International Experience. * See the attached detailed Office action for the international Experience.	uments have been received. uments have been received in Ap e priority documents have been r Bureau (PCT Rule 17.2(a)).	plication No eceived in this National Stage	
Attachment(s) 1) ☑ Notice of References Cited (PTO-892) 2) ☑ Notice of Draftsperson's Patent Drawing Review (PTO-9-	48) Paper No(s)	mmary (PTO-413) Mail Date	
3) Information Disclosure Statement(s) (PTO-1449 or PTO/ Paper No(s)/Mail Date <u>6/30/03</u> .		ormal Patent Application (PTO-152)	

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DETAILED ACTION

Claim Rejections - 35 USC § 112

1. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 19-28 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Claim 19 recites the limitation "the <u>photoresist</u> filler material" in lines 7-8. There is insufficient antecedent basis for this limitation in the claim.

Note that if antecedent basis is provided for this limitation, then claim 21 will not further limit claim 19.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-7 and 19-28 are rejected under 35 U.S.C. 102(b) as being anticipated by JP 6-302794 (JP '794). JP '794 discloses a method of manufacturing a solid-state image sensing element comprising the steps of forming a flattening layer on a substrate having a recessed bonding pad section containing an aluminum electrode, applying a photosensitive resin layer as a lens layer on the flattening layer, forming rectangular

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patterns by photolithography, heat flowing the rectangular patterns to form microlenses, forming a spin-on-glass layer, forming a resist layer for boring a pad window, patterning the resist layer, and etching the glass layer and the flattening layer to form a pad window. See the abstracts and Figure 1(A)-(E).

- 3. Claims 9-10 and 12-17 are rejected under 35 U.S.C. 102(e) as being anticipated by US 5,426,058 (US '058). US '058 discloses a method of manufacturing a solid-state imaging device comprising the steps of smoothing the surface of a semiconductor substrate by embedding a polymeric or polymerizable material into recessed portions in the surface, forming microlenses on the substrate, and cutting the substrate along scribe lines that constitute parts of the recessed portions. See the abstract and column 3, line 42 to column 4, line 68.
- 4. Claims 1-18 are rejected under 35 U.S.C. 102(b) as being anticipated by the abstract of KR 2001-010306 (KR '306). KR '306 discloses a method of making a charge coupled device having microlenses comprising the steps of forming a first planarized layer on a semiconductor substrate, forming a second planarized on layer on the first planarized layer, and forming microlenses on the second planarized layer, wherein the first planarized layer and the microlenses are formed of positive photoresist. See the abstract and the figure.

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5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to John A. McPherson whose telephone number is (571) 272-1386. The examiner can normally be reached on Monday through Friday, 8:00 AM to 4:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Mark Huff can be reached on (571) 272-1385. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

John A. McPherson Primary Examiner Art Unit 1756

JAM 6/26/04